



20V Complementary Enhancement Mode MOSFET - ESD Protected

Voltage

20/-20V

Current

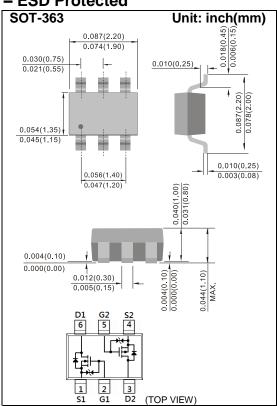
0.5/-0.5A

Features

- Low Voltage Drive (1.2V)
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-363 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0002 ounces, 0.006 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	20	-20	>
Gate-Source Voltage		V_{GS}	<u>+</u> 10	<u>+</u> 10	V
Continuous Drain Current		I _D	0.5	-0.5	Α
Pulsed Drain Current (Note 4)		I _{DM}	1.0	-1.0	А
	T _a =25°C	_	350		mW
Power Dissipation	Derate above 25°C	P_{D}	2.8		mW/°C
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150		°C
Typical Thermal resistance					
- Junction to Ambient (Note 3)		$R_{ heta JA}$	357		°C/W





N-Channel Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D = 250uA	20	-	ı	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.3	0.65	0.9	V
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} = 4.5V, I_{D} = 500mA	-	280	400	mΩ
		V_{GS} = 2.5V, I_{D} = 200mA	-	350	650	
		V_{GS} = 1.8V, I_{D} = 100mA	-	400	800	
		V_{GS} = 1.5V, I_{D} = 50mA	-	500	1200	
		V_{GS} = 1.2V, I_{D} = 20mA	-	700	3000	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =16V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\underline{+}8V, V_{DS}=0V$	-	<u>+</u> 0.5	<u>+</u> 10	uA
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	V _{DS} =10V, I _D =500mA, V _{GS} =4.5V ^(Note 1,2)	-	1.4	ı	
Gate-Source Charge	Q_{gs}		-	0.22	ı	nC
Gate-Drain Charge	Q_gd		-	0.21	-	
Input Capacitance	Ciss		-	67	-	pF
Output Capacitance	Coss	V_{DS} =10V, V_{GS} =0V, f =1.0MHZ	-	19	-	
Reverse Transfer Capacitance	Crss	I=1.UIVIDZ	-	6	1	
Switching						
Turn-On Delay Time	td _(on)	V_{DD} =10V, I_{D} =150mA, V_{GS} =4.0V, R_{G} =10 Ω (Note 1,2)	-	2.8	-	
Turn-On Rise Time	tr		-	20	-	no
Turn-Off Delay Time	td _(off)		-	23	-	ns
Turn-Off Fall Time	tf		-	23	-	
Drain-Source Diode						
Maximum Continuous Drain-Source				_	500	mA
Diode Forward Current	I _S		-	-	500	IIIA
Diode Forward Voltage	V_{SD}	I _S = 500mA, V _{GS} =0V	-	0.87	1.3	V





P-Channel Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D = -250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-0.3	-0.6	-1	V
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} = -4.5V, I_{D} =-500mA	ı	850	1200	mΩ
		V _{GS} = -2.5V, I _D =-200mA	1	990	1500	
		V _{GS} = -1.8V, I _D =-100mA	1	1160	2200	
		V_{GS} = -1.5V, I_{D} = -50mA	ı	1330	3600	
		V_{GS} = -1.2V, I_{D} = -10mA	1	1500	6000	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-16V, V _{GS} =0V	1	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	<u>+</u> 2	<u>+</u> 10	uA
Dynamic ^(Note 5)						
Total Gate Charge	Q_{g}	V_{DS} =-10V, I_{D} =-500mA, V_{GS} =-4.5V (Note 1,2)	1	1.4	-	nC
Gate-Source Charge	Q_gs		-	0.19	-	
Gate-Drain Charge	Q_{gd}		1	0.2	-	
Input Capacitance	Ciss	V _{DS} =-10V, V _{GS} =0V,	ı	38	-	pF
Output Capacitance	Coss		1	15	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	1	9	-	
Switching						
Turn-On Delay Time	td _(on)	V_{DD} =-10V, I_{D} =-500mA, V_{GS} =-4.5V, R_{G} =6 Ω (Note 1,2)	ı	7.2	-	ns
Turn-On Rise Time	tr		1	21	-	
Turn-Off Delay Time	td _(off)		1	85	-	
Turn-Off Fall Time	tf		-	116	-	
Drain-Source Diode						
Maximum Continuous Drain-Source		I _S			500	
Diode Forward Current	IS		•	-	-500	mA
Diode Forward Voltage	V_{SD}	I _S =-500mA, V _{GS} =0V	1	-0.93	-1.3	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





N-Channel TYPICAL CHARACTERISTIC CURVES

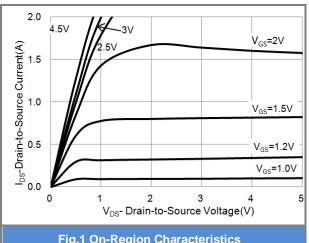


Fig.1 On-Region Characteristics

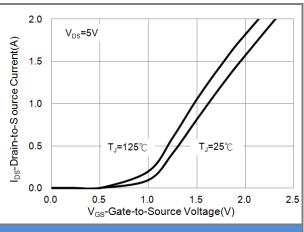


Fig.2 Transfer Characteristics

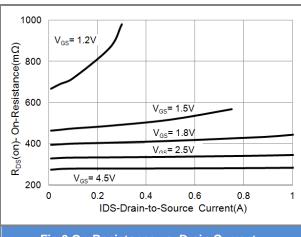


Fig.3 On-Resistance vs. Drain Current

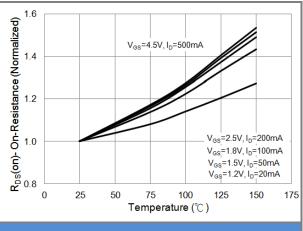
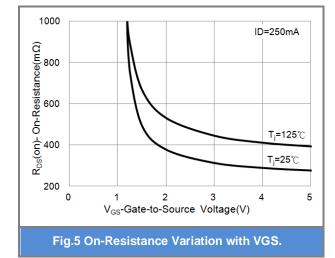


Fig.4 On-Resistance vs. Junction temperature



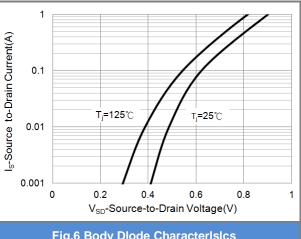


Fig.6 Body Dlode CharacterIslcs





N-Channel TYPICAL CHARACTERISTIC CURVES

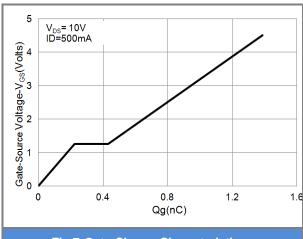


Fig.7 Gate-Charge Characteristics

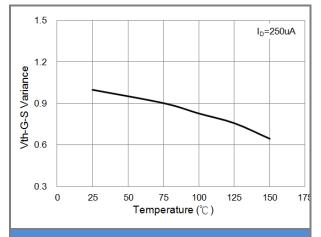


Fig.8 Threshold Voltage Variation with Temperature.

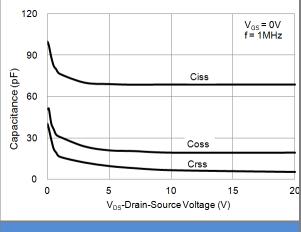


Fig.9 Capacitance vs. Drain-Source Voltage.





P-Channel TYPICAL CHARACTERISTIC CURVES

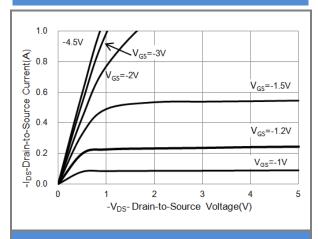


Fig.1 On-Region Characteristics

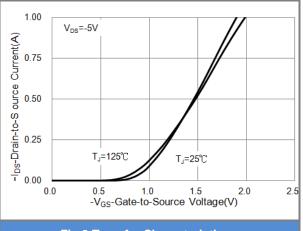


Fig.2 Transfer Characteristics

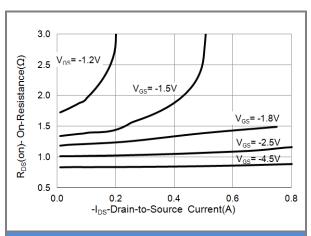


Fig.3 On-Resistance vs. Drain Current

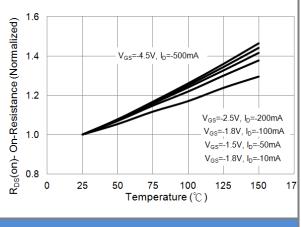
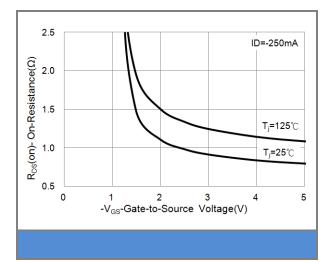
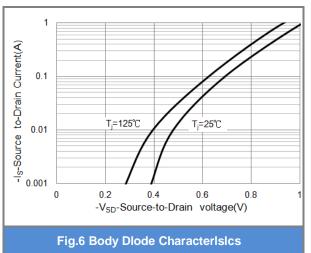


Fig.4 On-Resistance vs. Junction temperature









P-Channel TYPICAL CHARACTERISTIC CURVES

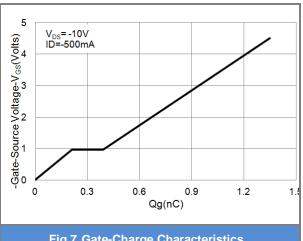


Fig.7 Gate-Charge Characteristics

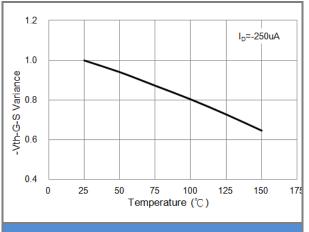


Fig.8 Threshold Voltage Variation with Temperature.

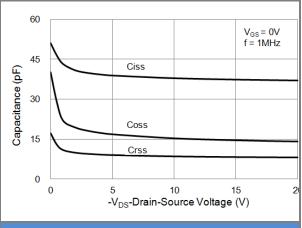


Fig.9 Threshold Voltage Variation with Temperature.

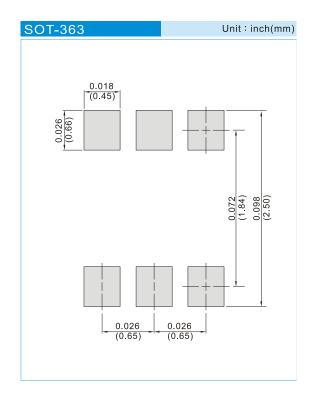




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJT7601_R1_00001	SOT-363	3K pcs / 7" reel	T61	Halogen free
PJT7601_R2_00001	SOT-363	10K pcs / 13" reel	T61	Halogen free

MOUNTING PAD LAYOUT







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